GS2231A

3A Ultra-Low Dropout Voltage Regulator

Product Description

The GS2231A is a 3A low dropout linear regulator designed for low dropout and high current applications. This device works with dual supplies, a control input for the control circuitry and a power input as low as 1.05V for providing current to output. It features 3A output current and ultra-low-drop output voltage as well as full protection functions. Vout can be as low as 0.8V. The other features include soft start, under voltage protection, current limit protection, Power-On-Reset function, and over temperature protection. The GS2231A is available in DFN3x3-10L and PSOP8 packages.

Features

- VIN Range 1.05V to 5.5V
- Adjustable Output Voltages to 0.8V Min
- 250mV Typical Dropout at 3A
- Current Limit Protection
- Thermal Shutdown Protection
- Vout Power OK Signal
- VOUT Pull Low Resistance when Disabled
- RoHS Compliant

Applications

- Notebook, Netbook, Graphic Cards
- Low Voltage Logic Supplies
- Chipset Supplies
- SMPS Post Regulators

Function Block Diagram





GS2231A

Pin Configuration & Description

	TOP VIEW				
POK 1 0 1 8 GND Vout 1 10 vcc EN 2 1 7 FB Vout 3 10 vin VIN 3 1 6 VOUT 5 NC Pok 5 10 10 VCC 4 1 5 NC Pok 5 10 10 10					
		PSOP-8	DFN3x3-10L		
Pin Name	Pin No. (PSOP-8)	Pin No. (DFN3x3-10L)	Pin Function		
Ροκ	1	5	Power OK indication, open drain output.		
EN	2	6	Enable pin. Internal pull high to Vcc		
V _{IN}	3	7,8&9	Supply input of power.		
V _{cc}	4	10	Supply input of control circuit.		
N.C.	5	-	Non connection		
Vout	6	1, 2 & 3	Output Voltage		
FB	7	4	Feedback Pin		
GND	8 & 9 (Exposed Pad)	11 (Exposed Pad)	Ground Pin (The exposed pad must be soldered to a PCB and be connected to GND for maximum power dissipation.)		

Ordering and Marking Information

Dort	Package	Marking Information				
Number		Product Code	Package Code	Lead Free	GS Code	
GS2231APSF	PSOP-8	GS2231A	PS	F	XXXX	
GS2231AZFF	DFN3x3-10L	GS2231A	ZF	F	XXXX	



Absolute Maximum Ratings

Supply Voltage, V	-0.3V ~ 6V	
Supply Voltage fo	-0.3V ~ 6V	
Other Pins		-0.3V ~ (Vcc + 0.3V)
Maximum Junction	n Temperature, TJ	150°C
Power Dissipation	I, PD	2.2W
Junction-to-Ambie	55°C/W	
Junction-to-Case	Thermal Resistance, θ _{JC}	20 °C/W
Lead Temperature	e (Soldering, 10 sec)	300°C
Storage Temperature Range		-65°C to 150°C
	НВМ	2KV
ESD Rating	MM	200V

Note1: Stresses greater than those listed under Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions

Symbol	Parameter	Range	Unit
V _{IN}	Supply Voltage	1.05 ~ V _{CC}	V
Vcc	Supply Voltage for Control Circuit (V _{CC} > V _{OUT} + 1.5V)	3.0 ~ 5.5	V
lout	Output Current	0 ~ 3	Α
R2	Refer to Typical Application Circuit	10K	Ω
TA	Ambient Temperature Range	-40 ~ 85	٥C

Electrical Characteristics

 $V_{CC}\text{=}~5V$ and $T_{A}\text{=}~25^{o}C,$ unless otherwise specified.

Symbol	Parameters	Condition	Min	Тур	Max	Units
Vcc	Vcc Operating Range		3.0		5.5	V
Vcc_por	Vcc POR Threshold	V _{CC} Rising	2.2	2.8	3.0	V
ΔV_{CC_POR}	Vcc POR Hysteresis	Vcc Falling	-	0.4	-	V
VIN	VIN Operating Range		1.05		Vcc	V
VIN_POR	VIN POR Threshold	V _{IN} Rising	0.8	-	1.0	V
$\Delta V_{\text{IN}_{POR}}$	VIN POR Hysteresis	V _{IN} Falling	-	0.35	-	V
ΙQ	Quiescent Current	VIN=VCC=VEN=5.0V IOUT=0A	-	0.9	1.5	mA
Icc_sd	Control Input Current in Shutdown	VIN=Vcc=5.0V VEN=0V	-	10	30	μΑ
VREF	Reference Voltage of FB		0.785	0.8	0.815	V
ΔV_{LOAD}	Load Regulation	VIN=VCC=VEN=5.0V IOUT=0 to 3A	-	0.1	0.5	%/A
ΔV _{LINE}	Line Regulation	V _{CC} =V _{EN} =5.0V I _{OUT} =1mA V _{IN} =1.05 to 5.0V	-	0.01	0.1	%/V



Symbol	Parameters	Condition	Min	Тур	Max	Units
Vdrop	Dropout Voltage	Vоит=1.6V I _{ОИТ} =3А	-	250	360	mV
I _{LIM}	Current Limit	-		5.5	-	А
R _{PULL}	VOUT Pull-Low Resistance	V _{EN} =0V	· ·	-	150	Ω
tss	Output Voltage Ramp Up Time		0.6	1	2	ms
Enable						
IEN	EN Input Bias Current	V _{EN} =0V	-	5	10	μA
Venl		Logic-Low Voltage	-	-	0.3	V
Venh	Enable Inreshold	Logic-High Voltage	1.1	-	-	
Power OK						
POK_H	POK High Threshold	V _{FB} Rising	-	92	-	%
POK_L	POK Low Threshold	V _{FB} Falling	-	82	-	%
V _{POKL}	POK Sink Voltage	Sink Current 5mA	-	-	0.4	V
t _{POK_DT}	POK Delay Time	•	0.5	1.5	5	ms
Thermal Pr	otection					
T _{SD}	Thermal Shutdown Temperature	-	•	165	-	°C
ΔT_{SD}	Thermal Shutdown Hysteresis		-	30	-	٥C

Electrical Characteristics (Continued)



Typical Performance Characteristics

 $V_{\text{IN}}=V_{\text{CC}}=5V,~V_{\text{OUT}}=0.8V,~C_{\text{IN}}=C_{\text{OUT}}=10\mu\text{F}$ and $T_{\text{A}}=25^{\circ}\text{C},$ unless otherwise specified.









IQ vs. Temperature

(Vcc=5V, VIN=3.3V, Vout=1.6V and Iout=1mA)

Typical Application Circuit



Application Information

Output Voltage Setting

The output voltage is programmed by the resistor divider connected to the FB pin. The preset output voltage is calculated by the following equation :

$$Vout = 0.8 \cdot \left(1 + \frac{R1}{R2}\right)$$
(V)

Where R1 is the resistor connected from V_{OUT} to FB with Kelvin sensing connection and R2 is the resistor connected from FB to GND and the 10Kohm is recommended typically.

Enable Control

A logic Low signal applied to this pin shuts down the output. A logic High signal enables the device to output a regulated power when V_{CC} and V_{IN} power supplies are ready. Enable pin is pulled high to V_{CC} internally.

Power-OK and Delay

The power okay pin is an open-drain output and a $100k\Omega$ pull up resistor has to be used to connect between POK pin to V_{OUT} to obtain an effective signal.

As the V_{FB} rises and reaches the rising Power-OK voltage threshold, an internal delay function starts to work. At the end of the delay time, the POK output HIGH to indicate the output is ok.

As the V_{FB} falls and reaches the falling Power-OK voltage threshold, the POK output LOW.



Application Information (Continued)

Power-On-Reset

A Power-On-Reset (POR) circuit monitors both of supply voltages on V_{CC} and V_{IN} pins to prevent wrong logic controls. The POR function initiates a soft-start process after both of the supply voltages exceed their rising POR voltage thresholds during powering on.

Soft-Start

An internal soft-start function controls rise rate of the output voltage to limit the current surge during start-up. The typical soft-start interval is about 1.0ms.

Current-Limit Protection

The GS2231A monitors the current flowing through the output NMOS and limits the maximum current to prevent load and GS2231A from damages during current overload conditions.

Thermal Shutdown Protection

Thermal protection limits power dissipation to prevent IC over temperature.

When the junction temperature exceeds 165°C, the over temperature protection circuit starts the thermal shutdown function and turns the pass transistor off. The pass transistor turns on again after the junction temperature cools by 30°C.



Package Information

PSOP-8



DIMENSION D DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 mm PER END. DIMENSION E1 DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 mm PER SIDE.

	Dimensions					
	Millir	neters	Inc	hes		
STMBOL	MIN	MAX	MIN	MAX		
Α		1.75		0.069		
A1	0.10	0.15	0.004	0.006		
A2	1.25		0.049			
b	0.31	0.51	0.012	0.020		
С	0.10	0.25	0.004	0.010		
D	4.70	5.10	0.185	0.201		
D1	1.50		0.059			
E	5.80	6.20	0.228	0.244		
E1	3.80	4.00	0.150	0.157		
E2	1.00		0.039			
е	1.27 BSC		0.050	BSC		
L	0.4	1.27	0.016	0.050		
θ	0°	8°	0°	8°		



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Package Information

DFN3X3-10







DIMENSION D AND E1 DO NOT INCLUDE MOLD FLASH, TIE BAR BURRS , GATE BURRS , AND INTERLEAD FLASH, NOT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE PLASTIC BODY

	Dimensions					
	Millir	neters	Inc	hes		
STMBOL	MIN	MAX	MIN	MAX		
Α	0.70	0.80	0.028	0.031		
A1	0.00	0.05	0.000	0.002		
b	0.18	0.30	0.007	0.012		
D	2.90	3.10	0.114	0.122		
D2	2.20	2.70	0.087	0.106		
E1	2.90	3.10	0.114	0.122		
E2	1.40	1.80	0.055	0.071		
е	0.50 BSC		0.020	BSC		
L	0.30	0.50	0.012	0.020		



GS2231A

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